DATA SHEET

NEC

NPN SILICON GERMANIUM RF TRANSISTOR

NESG240033

NPN SiGe RF TRANSISTOR FOR UHF-BAND, LOW NOISE, LOW DISTORTION AMPLIFICATION 3-PIN MINIMOLD (33 PKG)

FEATURES

- The device is an ideal choice for low noise, low distortion amplification.
  NF = 0.75 dB TYP. @ V_{CE} = 5 V, I_C = 15 mA, f = 1 GHz
- $P_{O\ (1\ dB)}$ = 23.5 dBm TYP. @ V_{CE} = 5 V, $I_{C\ (set)}$ = 40 mA, f = 1 GHz
- OIP_3 = 35.5 dBm TYP. @ V_{CE} = 5 V, $I_{C\ (set)}$ = 40 mA, f = 1 GHz
- Maximum stable power gain: MSG =13.0 dB TYP. @ V_{CE} = 5 V, I_C = 40 mA, f = 1 GHz
- SiGe HBT technology (UHS2) : f_T = 10.5 GHz
- This product is improvement of ESD of NESG2xxx series.
- 3-pin minimold (33 PKG)

ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Supplying Form
NESG240033	NESG240033-A	3-pin minimold (33 PKG) (Pb-Free)	50 pcs (Non reel)	• 8 mm wide embossed taping • Pin 3 (Collector) face the perforation side of the tape
NESG240033-T1B	NESG240033-T1B-A		3 kpcs/reel	

Remark To order evaluation samples, please contact your nearby sales office.
Unit sample quantity is 50 pcs.

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	V_{CBO}	5.5	V
Collector to Emitter Voltage	V_{CES}	13	V
Collector to Emitter Voltage	V_{CEO}	5.5	V
Base Current Note 1	I_B	36	mA
Collector Current	I_C	400	mA
<R> Total Power Dissipation	P_{tot} Note 2	480	mW
Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	−65 to +150	°C

Notes 1. Depend on the ESD protect device.

2. Mounted on 3.8 cm × 9.0 cm ×0.8 mm (t) glass epoxy PWB

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

THERMAL RESISTANCE (T_A = +25°C)

Parameter	Symbol	Ratings	Unit
<R> Termal Resistance from Junction to Ambient [Note]	Rth_{j-a}	260	°C/W

Note Mounted on 3.8 cm × 9.0 cm × 0.8 mm (t) glass epoxy PWB

RECOMMENDED OPERATING RANGE (T_A = +25°C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
<R> Collector Current	I_C	–	40	–	mA

ELECTRICAL CHARACTERISTICS (T_A = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	I_{CBO}	V_{CB} = 5 V, I_E = 0 mA	–	–	100	nA
Emitter Cut-off Current	I_{EBO}	V_{EB} = 0.4 V, I_C = 0 mA	–	–	100	nA
DC Current Gain	h_{FE} [Note 1]	V_{CE} = 5 V, I_C = 15 mA	140	180	260	–
RF Characteristics						
Gain Bandwidth Product	f_T	V_{CE} = 5 V, I_C = 40 mA, f = 1 GHz	–	10.5	–	GHz
Insertion Power Gain	$\|S_{21e}\|^2$	V_{CE} = 5 V, I_C = 40 mA, f = 1 GHz	9.5	11.5	–	dB
Noise Figure (1)	NF1	V_{CE} = 5 V, I_C = 15 mA, f = 1 GHz, $Z_S = Z_{Sopt}$, Z_L = 50Ω	–	0.75	1.15	dB
Noise Figure (2)	NF2	V_{CE} = 5 V, I_C = 40 mA, f = 1 GHz, $Z_S = Z_{Sopt}$, $Z_L = Z_{Lopt}$	–	0.8	–	dB
Associated Gain (1)	G_a1	V_{CE} = 5 V, I_C = 15 mA, f = 1 GHz, $Z_S = Z_{Sopt}$, Z_L = 50Ω	9.0	11.0	–	dB
Associated Gain (2)	G_a2	V_{CE} = 5 V, I_C = 40 mA, f = 1 GHz, $Z_S = Z_{Sopt}$, $Z_L = Z_{Lopt}$	–	12.0	–	dB
Reverse Transfer Capacitance	C_{re} [Note 2]	V_{CB} = 5 V, I_E = 0 mA, f = 1 MHz	–	0.9	1.1	pF
Maximum Stable Power Gain	MSG [Note 3]	V_{CE} = 5 V, I_C = 40 mA, f = 1 GHz	11.0	13.0	–	dB
Gain 1 dB Compression Output Power	$P_{O\ (1\ dB)}$	V_{CE} = 5 V, $I_{C\ (set)}$ = 40 mA, f = 1 GHz, $Z_S = Z_{Sopt}$, $Z_L = Z_{Lopt}$	–	23.5	–	dBm
Output 3rd Order Intercept Point	OIP_3	V_{CE} = 5 V, $I_{C\ (set)}$ = 40 mA, f = 1 GHz, Δf = 1 MHz, $Z_S = Z_{Sopt}$, $Z_L = Z_{Lopt}$	–	35.5	–	dBm

Notes 1. Pulse measurement: PW ≤ 350 μs, Duty Cycle ≤ 2%

2. Collector to base capacitance when the emitter grounded.

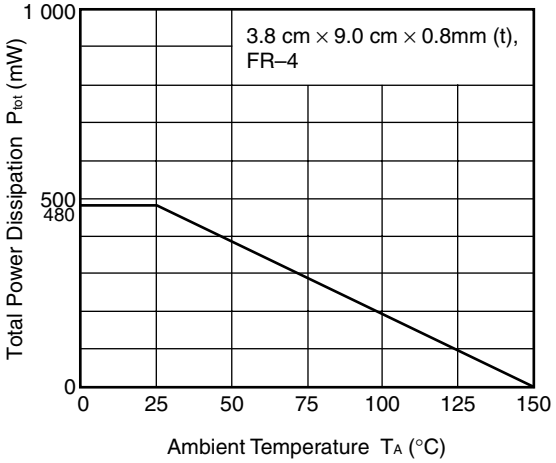
3. $MSG = \left|\frac{S_{21}}{S_{12}}\right|$

h_{FE} CLASSIFICATION

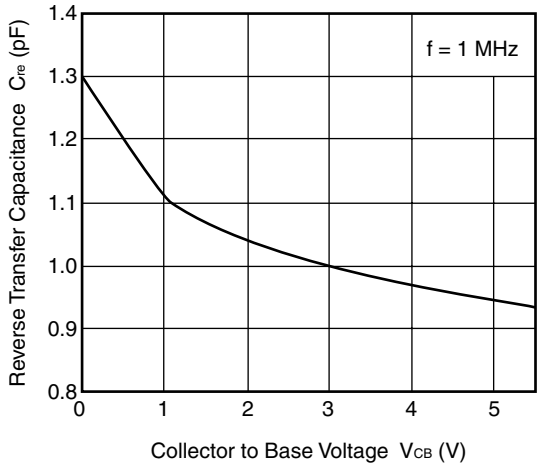
Rank	FB
Marking	R7A
h_{FE} Value	140 to 260

<R> **TYPICAL CHARACTERISTICS (T_A = +25°C, unless otherwise specified)**

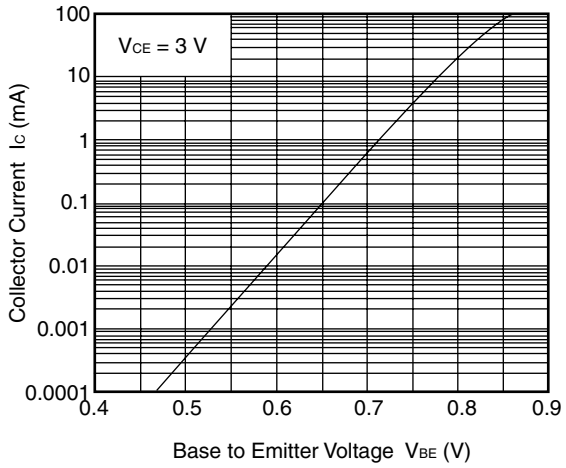
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



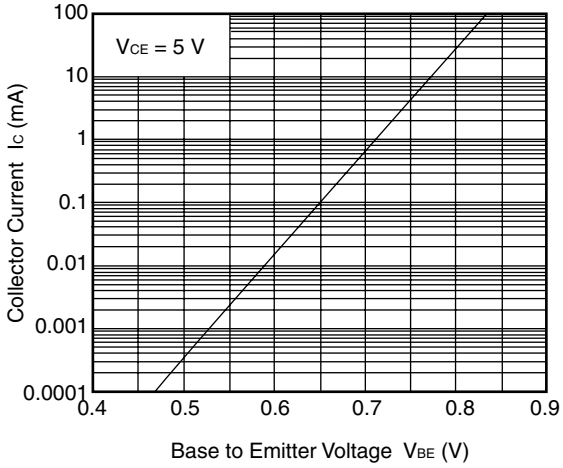
REVERSE TRANSFER CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



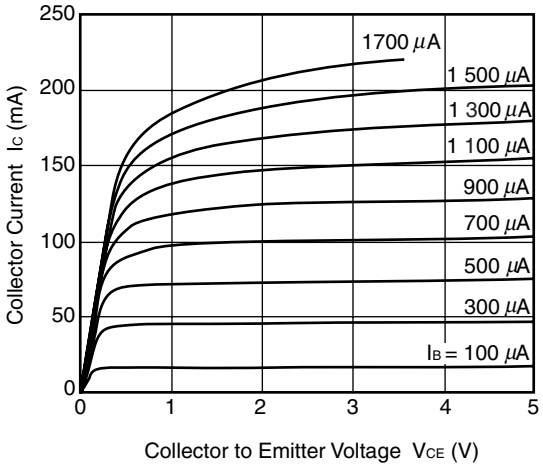
COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE



COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE

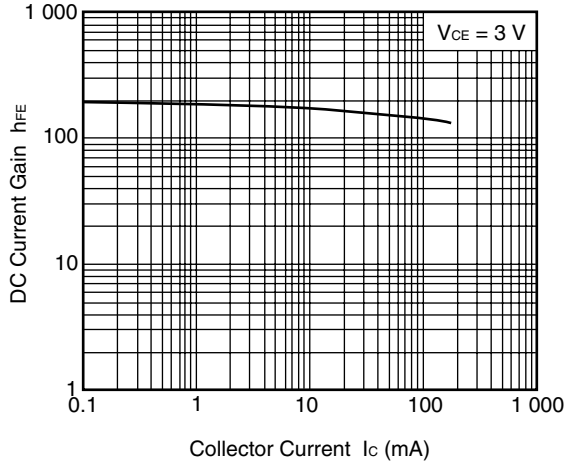


COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE

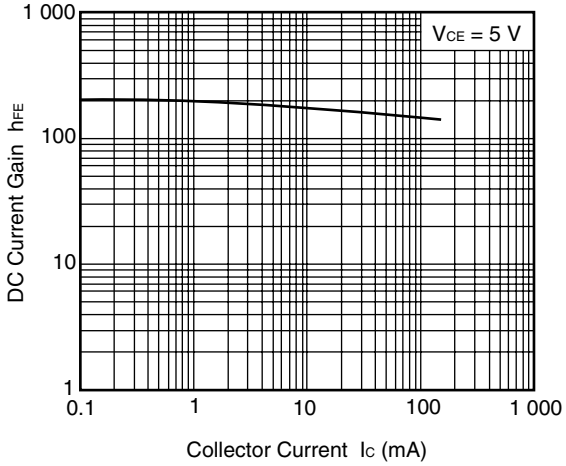


Remark The graphs indicate nominal characteristics.

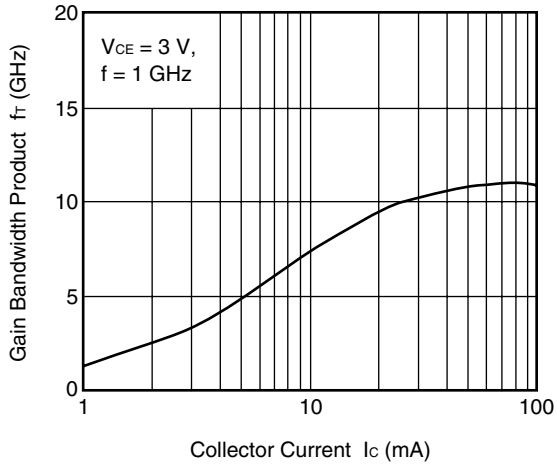
DC CURRENT GAIN vs.
COLLECTOR CURRENT



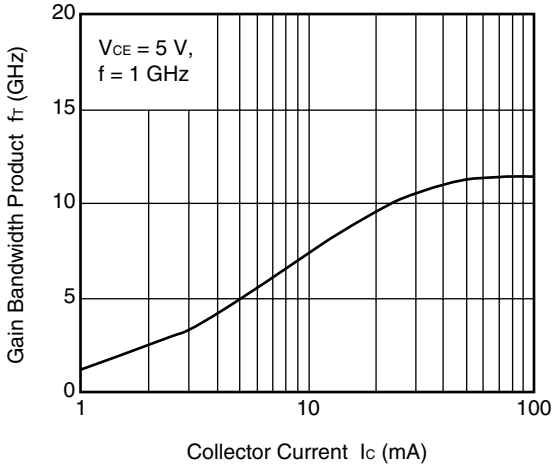
DC CURRENT GAIN vs.
COLLECTOR CURRENT



GAIN BANDWIDTH PRODUCT
vs. COLLECTOR CURRENT

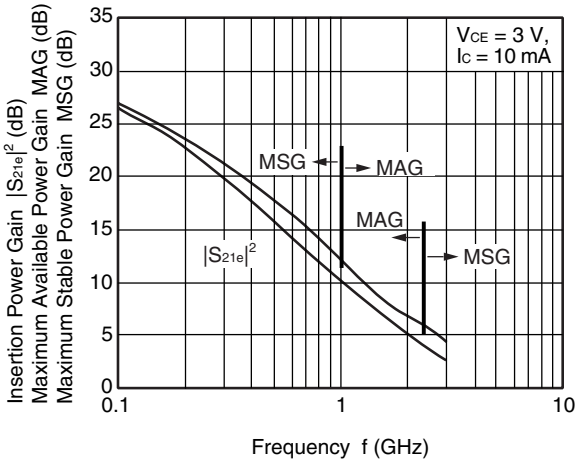


GAIN BANDWIDTH PRODUCT
vs. COLLECTOR CURRENT

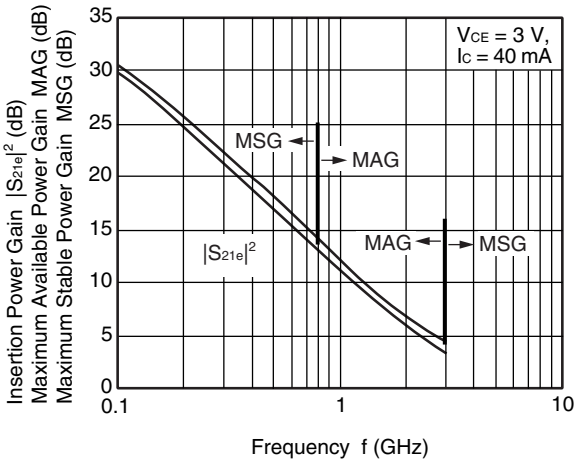


Remark The graphs indicate nominal characteristics.

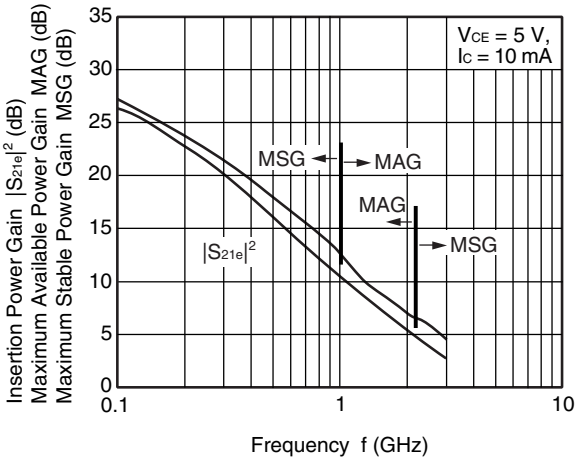
INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY



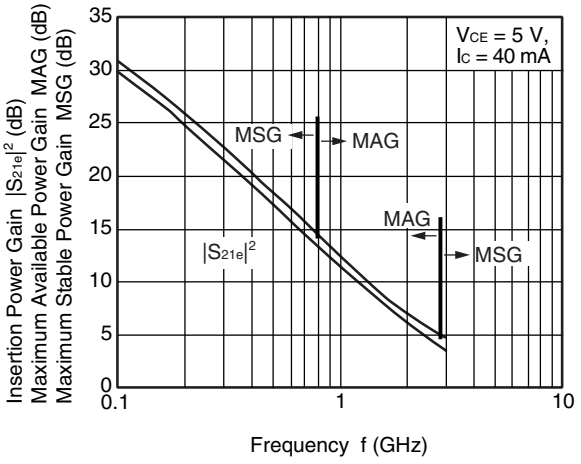
INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY



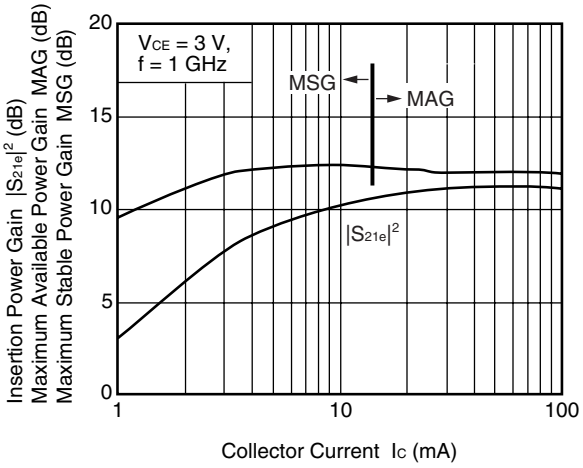
INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY



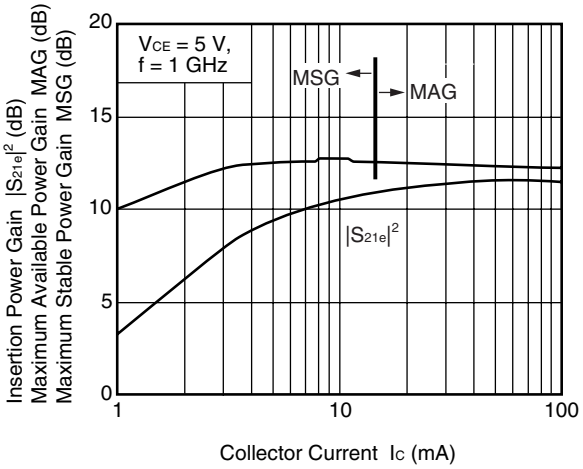
INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY



INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT

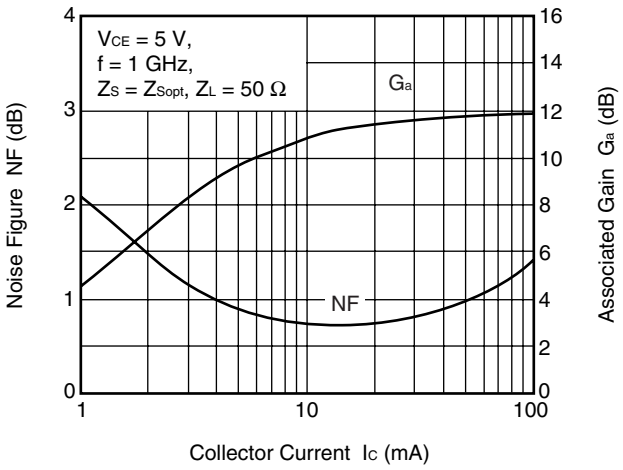


INSERTION POWER GAIN, MAG, MSG vs. COLLECTOR CURRENT

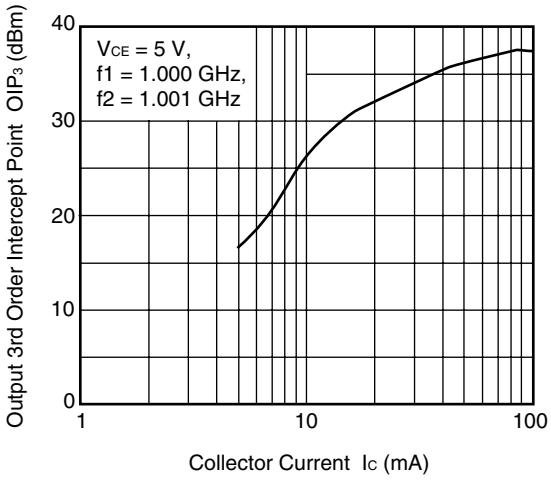


Remark The graphs indicate nominal characteristics.

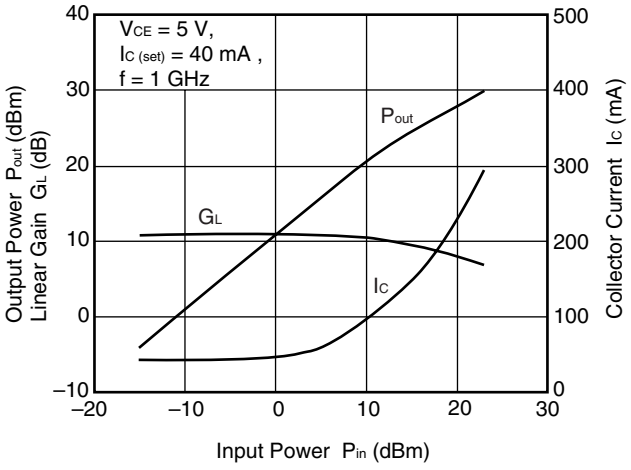
NOISE FIGURE, ASSOCIATED GAIN vs. COLLECTOR CURRENT



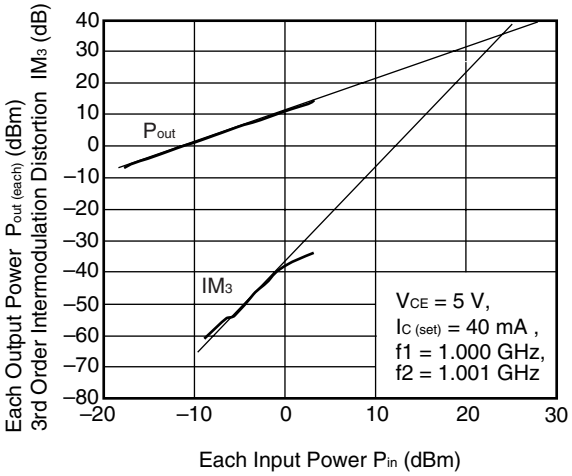
OUTPUT 3RD ORDER INTERCEPT POINT vs. COLLECTOR CURRENT



OUTPUT POWER, LINEAR GAIN, COLLECTOR CURRENT vs. INPUT POWER



EACH OUTPUT POWER, IM3 vs. EACH INPUT POWER



Remark The graphs indicate nominal characteristics.

S-PARAMETERS

S-parameters and noise parameters are provided on our Web site in a format (S2P) that enables the direct import of the parameters to microwave circuit simulators without the need for keyboard inputs.

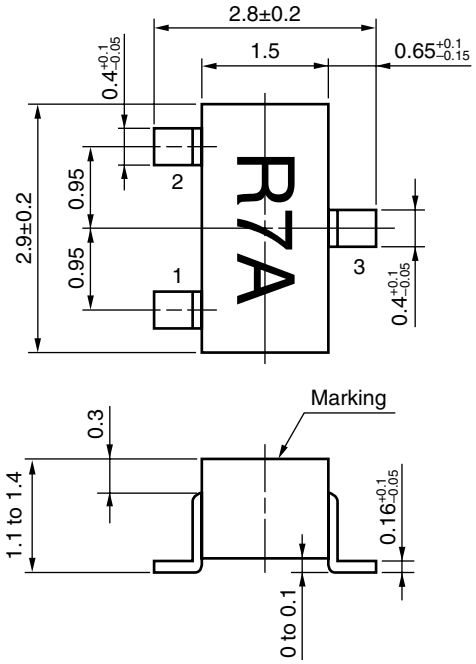
Click here to download S-parameters.

[RF and Microwave] → [Device Parameters]

URL http://www.necel.com/microwave/en/

PACKAGE DIMENSIONS

3-PIN MINIMOLD (33 PKG) (UNIT: mm)



PIN CONNECTIONS

1. Emitter
2. Base
3. Collector

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